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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/533,613	03/22/2000	Fred E. Stanke	21964-708	7897
:	7590 02/17/2004		EXAMINER	
MICHAEL A STALLMAN			PHAM, HOA Q	
STALLMAN & POLLOCK LLP 121 SPEAR STREET			ART UNIT	PAPER NUMBER
SUITE 290			2877	
SAN FRANCI	SCO, CA 94105		DATE MAILED: 02/17/200-	4

Please find below and/or attached an Office communication concerning this application or proceeding.

	1 4 41 44 44	A	im
	Application No.	Applicant(s)	
Office Action Surrena	09/533,613	STANKE ET AL.	
Office Action Summary	Examiner	Art Unit	
	Hoa Q. Pham	2877	
The MAILING DATE of this communication Period for Reply	appears on the cover shee	t with the corresp ndence add	iress
A SHORTENED STATUTORY PERIOD FOR RE THE MAILING DATE OF THIS COMMUNICATIO  - Extensions of time may be available under the provisions of 37 CFF after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a  - If NO period for reply is specified above, the maximum statutory per  - Failure to reply within the set or extended period for reply will, by sta  - Any reply received by the Office later than three months after the may earned patent term adjustment. See 37 CFR 1.704(b).  Status	N. R 1.136(a). In no event, however, ma reply within the statutory minimum of riod will apply and will expire SIX (6) I atute, cause the application to becom	by a reply be timely filed  If thirty (30) days will be considered timely.  MONTHS from the mailing date of this core  BEANDONED (35 U.S.C. § 133).	
1) Responsive to communication(s) filed on 2	7 October 2003.		
2a)⊠ This action is <b>FINAL</b> . 2b)□ T	his action is non-final.		
3) Since this application is in condition for allocal closed in accordance with the practice under the condition of the co			merits is
Disposition of Claims			
4) Claim(s) 24-29 is/are pending in the application	ation.		
4a) Of the above claim(s) is/are without	drawn from consideration.		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>24-29</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction an	d/or election requirement.		
Application Papers			
9)☐ The specification is objected to by the Exam	niner.		
10)☐ The drawing(s) filed on is/are: a)☐ a	accepted or b)☐ objected	to by the Examiner.	
Applicant may not request that any objection to	the drawing(s) be held in abe	yance. See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the cor	·	= : :	
11)☐ The oath or declaration is objected to by the	Examiner. Note the attac	hed Office Action or form PT	O-152.
Priority under 35 U.S.C. §§ 119 and 120			
12) Acknowledgment is made of a claim for fore a) All b) Some * c) None of:  1. Certified copies of the priority document Certified copies of the priority document.  3. Copies of the certified copies of the priority document.	ents have been received. ents have been received i	n Application No	Stage
application from the International Bur  * See the attached detailed Office action for a  13) Acknowledgment is made of a claim for dome	reau (PCT Rule 17.2(a)). list of the certified copies i	not received.	
since a specific reference was included in the 37 CFR 1.78.	e first sentence of the spec	ification or in an Application [	
a) The translation of the foreign language			
14) Acknowledgment is made of a claim for dome reference was included in the first sentence of			
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(	5) Notice	ew Summary (PTO-413) Paper No(s of Informal Patent Application (PTO-	
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## **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 24-29 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kodera et al (5,695,601) in view of Norton et al (5,486,701) and Hignette et al (5,191,393).

Regarding claims 24 and 28, Kodera et al (of record) discloses a wafer processing station (20) and a metrology station (30) apart from but coupled to the processing station wherein the metrology station comprises an ultraviolet light source (column 3, lines 30-37) illuminating a measurement region of a surface of a wafer (10). (See figure 3). Kodera et al does not explicitly teach steps of: (1) measuring spectral content of the broadband light beam reflected from the wafer, (2) measuring the spectral content of the broadband light beam which has not been reflected from the wafer, and determining the wafer based on the first and second measurements; however, such a feature is known in the art, for example, as taught by Norton et al. Norton et al, from the same field of endeavor, teaches steps of: (1) measuring spectral content of the broadband light beam (46) reflected from the wafer (3) by detector (93), (2) measuring the spectral content of the broadband light beam (48) which has not been reflected from the wafer by detector (95), and determining the wafer based on the first and second

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measurements the measurements, where the second measurement is used to correct for system characteristics (correct for lamp noise) (see column 5 line 60 through column 6 line 20). It would have been obvious to one having ordinary skill in the art at the time the invention was made to replace the optical detection unit of Kodera et al by an optical inspection system of Norton et al. The rationale for this modification would have arisen from the fact that both systems are used for measuring the thickness of the wafer; a substitution one for another is generally recognized as being within the level of ordinary skill in the art. Hignette et al teaches that the light source (22) and fiber (8) are located outside of the metrology device (2) (see figures 1 and 7). It would have been obvious to one having ordinary skill in the art at the time the invention was made to include in Kodera et al and Norton et al an optical fiber so that the light source is located outside the measuring device as taught by Hignette et al. The rationale for this modification would have arisen from the fact that by locating the light source outside the device would avoid the harmful effects of the light source as suggested by Hignette et al (column 5, lines 62-68).

Regarding claim 25, Norton et al teaches that both beams (46, 48) pass through their respective spectrometer pinholes substantially parallel (column 3 lines 41-49).

Thus, the first and second measurements are obtained simultaneously.

Regarding claim 26, column 1, lines 18-19 of Norton et al for UV range.

Regarding claims 27 and 29, see column 2, lines 4-16 of Norton et al for the use of Xenon lamp, which covers from UV to near infrared.

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3. Claims 24-29 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kodera et al in view of Adams (4,899,055) and Hignette et al.

Regarding claims 24 and 28, Kodera et al (of record) discloses a wafer processing station (20) and a metrology station (30) apart from but coupled to the processing station wherein the metrology station comprises an ultraviolet light source (column 3, lines 30-37) illuminating a measurement region of a surface of a wafer (10). (See figure 3). Kodera et al does not explicitly teach steps of: (1) measuring spectral content of the broadband light beam reflected from the wafer, (2) measuring the spectral content of the broadband light beam which has not been reflected from the wafer, and determining the wafer based on the first and second measurements; however, such a feature is known in the art, for example, as taught by Adams. Adams, from the same field of endeavor, teaches steps of: (1) measuring spectral content of the UV-broadband light beam reflected from the wafer (24,26) by detector (28), (2) measuring the spectral content of the broadband light beam which has not been reflected from the wafer by detector (32), and determining the wafer based on the first and second measurements the measurements, where the second measurement is used to correct for system characteristics (monitoring the output 14 of the lamp 12) (see figure 2, column 5 lines 7-19, and column 2 lines 9-36). It would have been obvious to one having ordinary skill in the art at the time the invention was made to replace the optical detection unit of Kodera et al by an optical inspection system of Adams. The rationale for this modification would have arisen from the fact that both systems are used for measuring the thickness of the wafer; a substitution one for another is generally recognized as being within the level of

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ordinary skill in the art. Hignette et al teaches that the light source (22) and fiber (8) are located outside of the metrology device (2) (see figures 1 and 7). It would have been obvious to one having ordinary skill in the art at the time the invention was made to include in Kodera et al and Adams et al an optical fiber so that the light source is located outside the measuring device as taught by Hignette et al. The rationale for this modification would have arisen from the fact that by locating the light source outside the device would avoid the harmful effects of the light source as suggested by Hignette et al (column 5, lines 62-68).

Regarding claim 25, Adams teaches that both beams pass through their beam splitter (20) substantially parallel. Thus, the first and second measurements are obtained simultaneously.

Regarding claim 26, see abstract of Adams for UV range (240-300 nm).

Regarding claims 27 and 29, Adams teaches the use of Mercury lamp which covers UV range and does not teaches the use of Xenon lamp, which includes UV light and visible light. However, it would have been obvious to one having ordinary skill in the art to replace the lamp of Adams by a Xenon lamp because they are function in the same manner. In addition, using broader range would increase the advantage of the measurement.

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Golzarian (6,406,641) discloses a liquid etch endpoint detection and process metrology.

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5. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hoa Q. Pham whose telephone number is (571) 272-2426. The examiner can normally be reached on 6:30 AM to 5 PM, Monday through Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Frank G. Font can be reached on (571) 272-2415. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Hoa Q. Pham Primary Examiner Art Unit 2877

HP January 24, 2004